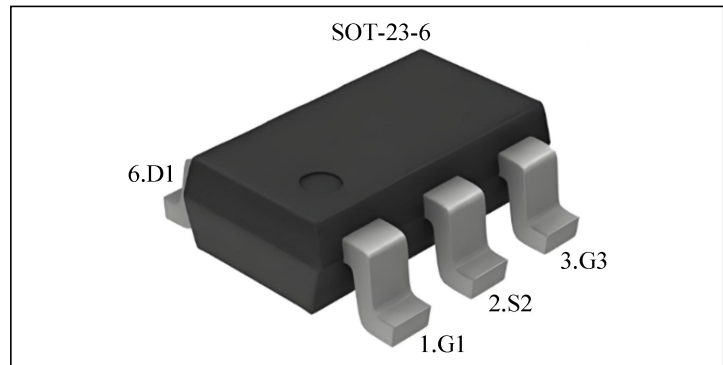


N and P-Channel Complementary Power MOSFET
Features

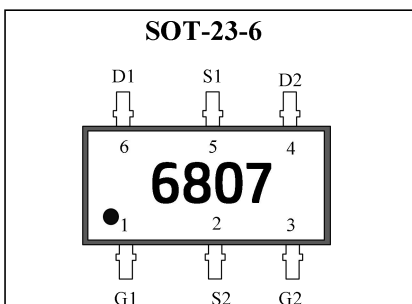
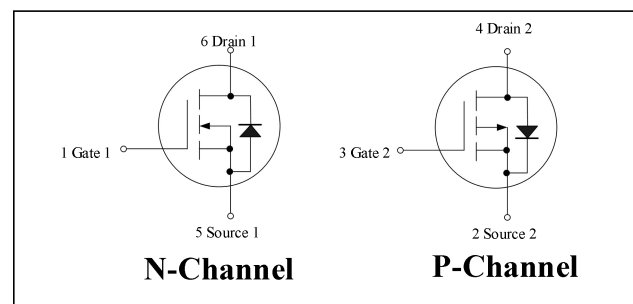
- N-Channel**
 $V_{DS}=30V, I_D=5.8A$
 $R_{DS(on)} < 41m\Omega @ V_{GS}=10V$
 $R_{DS(on)} < 45m\Omega @ V_{GS}=4.5V$
- P-Channel**
 $V_{DS}=-30V, I_D=-4.1A$
 $R_{DS(on)} < 60m\Omega @ V_{GS}=-10V$
 $R_{DS(on)} < 87m\Omega @ V_{GS}=-4.5V$
- High Power and Current handling capability


Mechanical Characteristics

- Package: SOT-23-6
- Packaging: Tape and Reel per EIA 481
- Marking : Making Code

Applications

- Motor Drive Applications
- Networking、Half/Full Bridge Topology

Marking : Making Code

Schematic Diagram

Absolute Maximum Rating(Ratings at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbols	N-Channel	P-Channel	Unit
Drain-Source Voltage	V_{DS}	30	-30	V
Gate-Source Voltage	V_{GS}	12	-20	V
Drain Current-Continuous	I_D	5.8	-4.1	A
Drain Current-Pulsed ^{Note1}	I_{DM}	30	-20	A
Junction Temperature	P_D	1.2		W
Maximum Power Dissipation	T_J	150		°C
Storage Temperature Range	T_{STG}	-55 to +150		°C

Thermal Characteristics

Thermal Resistance,Junction-to-Ambient Note2	$R_{\theta JA}$	89	°C/W
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N-Channel Electrical Characteristics(T_c=25°C Unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	30	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$	--	--	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 12V, V_{DS}=0V$	--	--	± 100	nA
Gate Threshold Voltage ^{Note3}	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.7	0.9	1.4	V
Drain-source on-resistance ^{Note3}	$R_{DS(on)}$	$V_{GS}=10V, I_D=5.8A$	--	28	41	m Ω
		$V_{GS}=4.5V, I_D=5A$	--	31	45	m Ω
Forward Transconductance ^{Note3}	g_{FS}	$V_{DS}=5V, I_D=5A$	10	--	--	S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1MHz$	--	820	--	pF
Output Capacitance	C_{oss}		--	99	--	pF
Reverse Transfer Capacitance	C_{rss}		--	77	--	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=15V, R_L=2.7\Omega$ $V_{GS}=10V, R_{GEN}=3\Omega$	--	3.3	--	nS
Turn-on Rise Time	t_r		--	4.8	--	nS
Turn-off Delay Time	$t_{d(off)}$		--	26	--	nS
Turn-off Fall Time	t_f		--	4	--	nS
Total Gate Charge	Q_g	$V_{DS}=15V, I_D=5.8A, V_{GS}=4.5V$	--	9.5	--	nC
Gate-Source Charge	Q_{gs}		--	1.5	--	nC
Gate-Drain Charge	Q_{gd}		--	3	--	nC
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note3}	V_{SD}	$V_{GS}=0V, I_S=5.8A$	--	--	1.2	V
Diode Forward Current ^{Note2}	I_S		--	--	5.8	A

P-Channel Electrical Characteristics(Tc=25°C Unless otherwise specified)

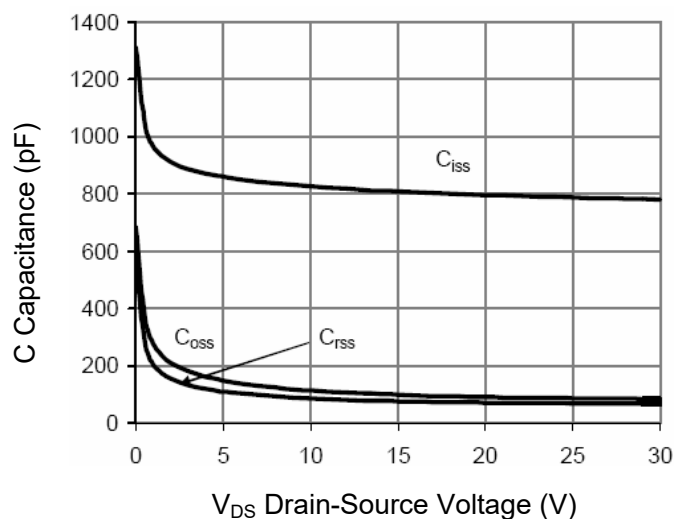
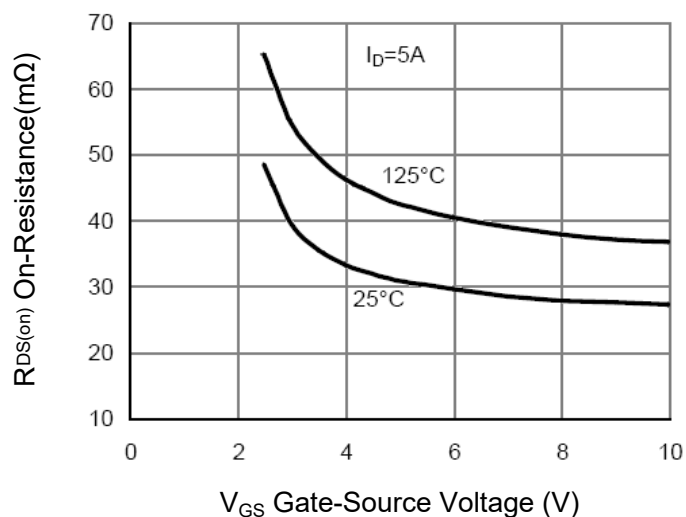
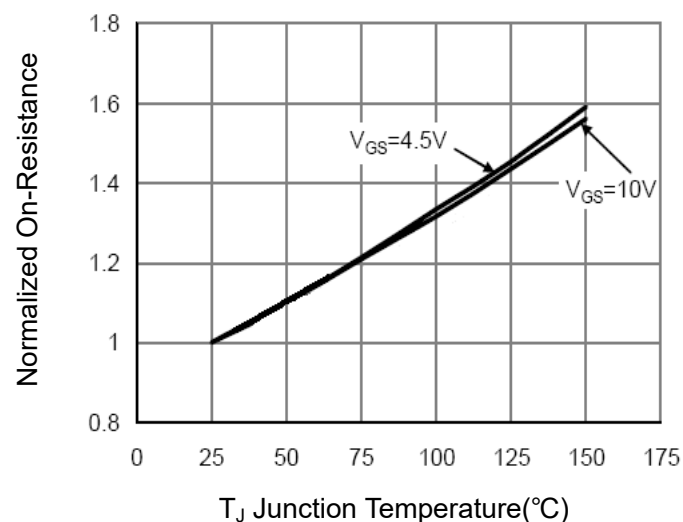
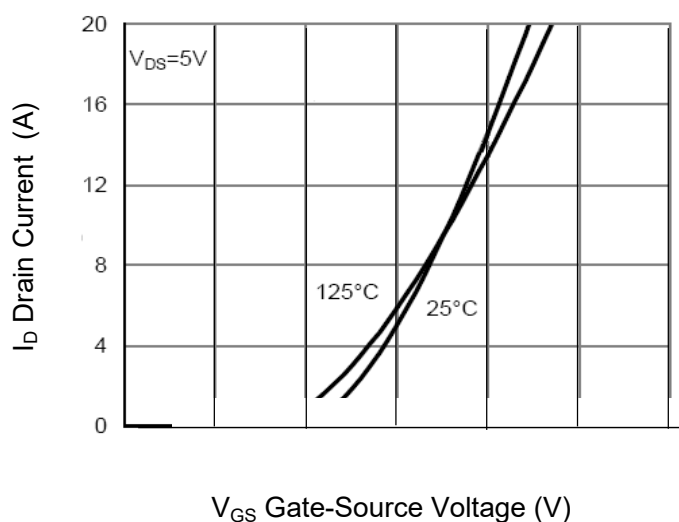
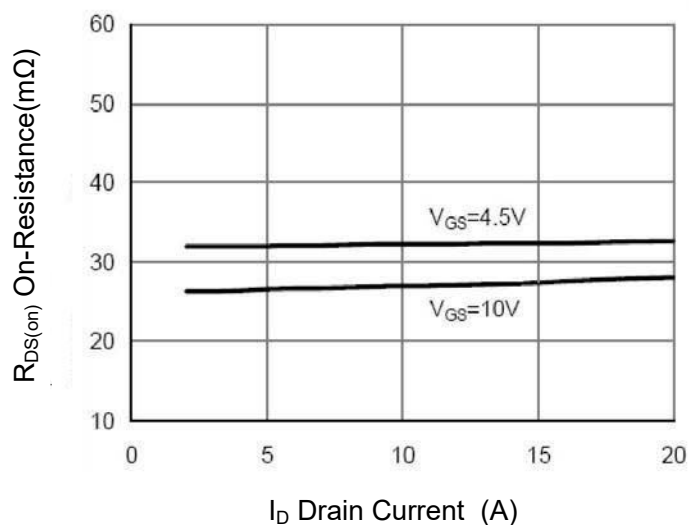
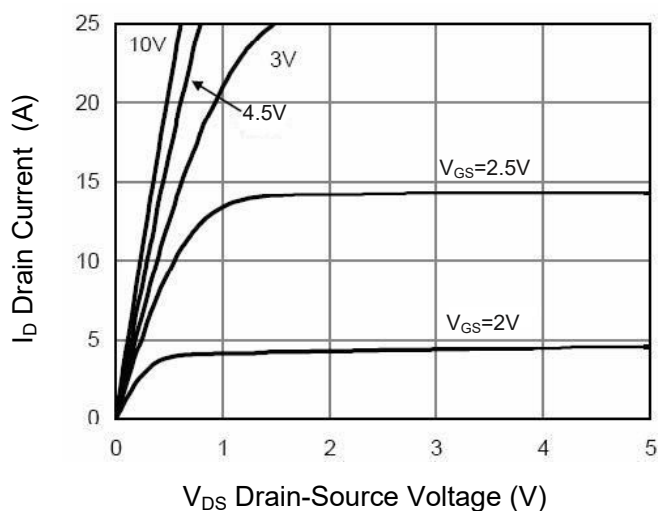
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$-V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	30	--	--	V
Zero Gate Voltage Drain Current	$-I_{DSS}$	$V_{DS}=-24V, V_{GS}=0V$	--	--	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	--	--	± 100	nA
Gate Threshold Voltage ^{Note3}	$-V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	1	1.4	3	V
Drain-source on-resistance ^{Note3}	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4.1A$	--	48	60	m Ω
		$V_{GS}=-4.5V, I_D=-3A$	--	60	87	m Ω
Forward Transconductance ^{Note3}	g_{FS}	$V_{DS}=-5V, I_D=-4A$	5.5	--	--	S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V, f=1MHz$	--	650	--	pF
Output Capacitance	C_{oss}		--	105	--	pF
Reverse Transfer Capacitance	C_{rss}		--	65	--	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-15V, R_L=3.6\Omega$ $V_{GS}=-10V, R_{CEN}=3\Omega$	--	8.5	--	nS
Turn-on Rise Time	t_r		--	4.5	--	nS
Turn-off Delay Time	$t_{d(off)}$		--	26	--	nS
Turn-off Fall Time	t_f		--	12.5	--	nS
Total Gate Charge	Q_g	$V_{DS}=-15V$ $I_D=-4.1A, V_{GS}=-10V$	--	12.5	--	nC
Gate-Source Charge	Q_{gs}		--	2.8	--	nC
Gate-Drain Charge	Q_{gd}		--	2.7	--	nC
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note3}	$-V_{SD}$	$V_{GS}=0V, I_S=-4.1A$	--	--	1.2	V
Diode Forward Current ^{Note2}	$-I_S$		--	--	4.1	A

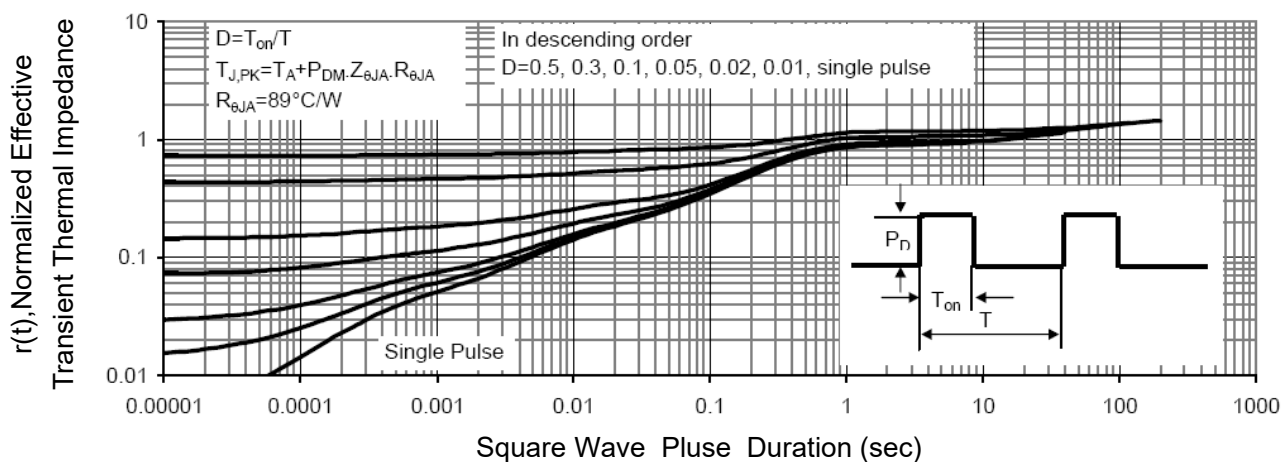
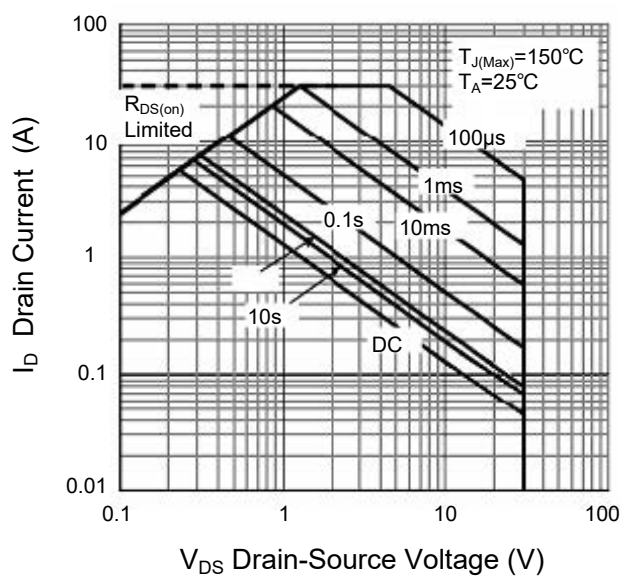
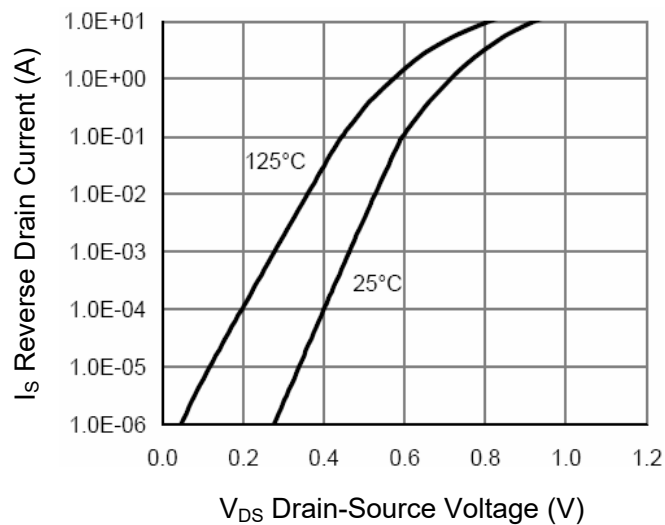
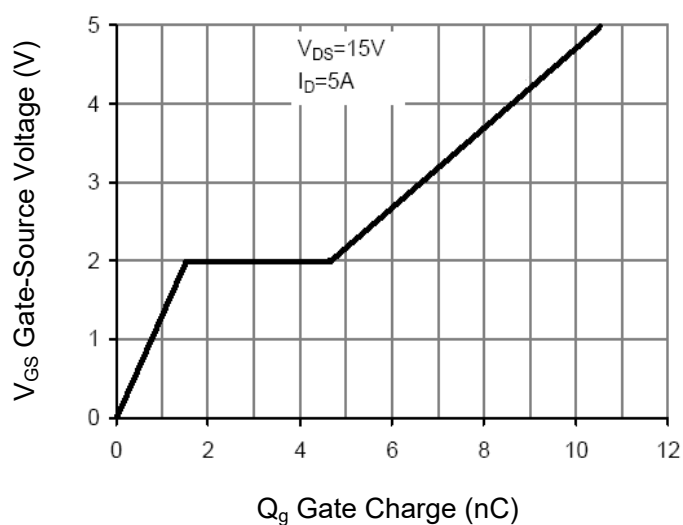
Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \leq 10$ sec.

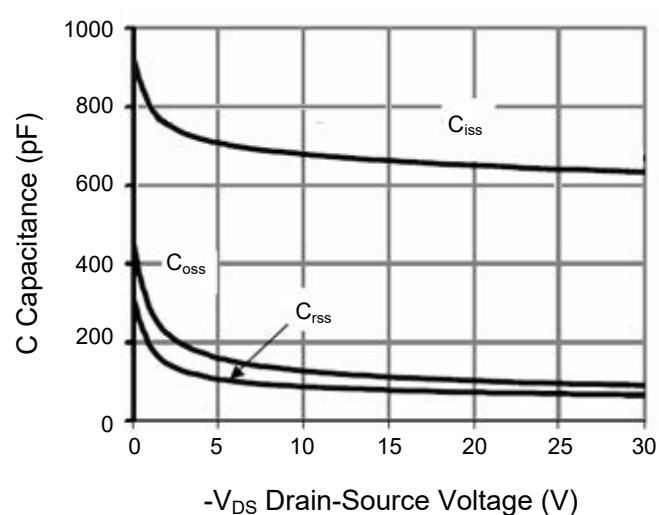
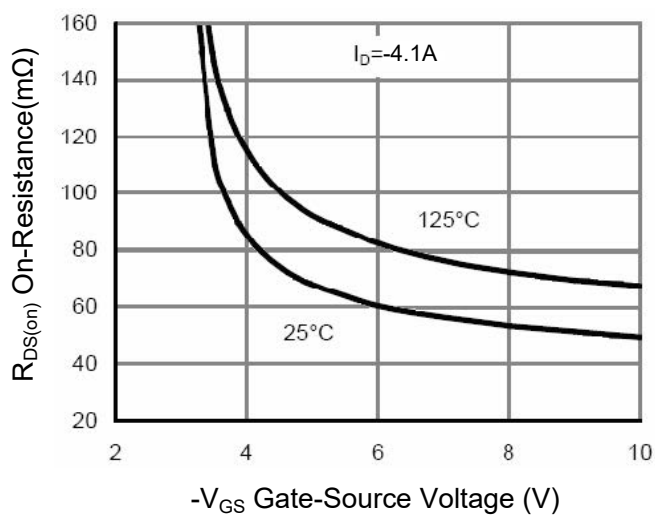
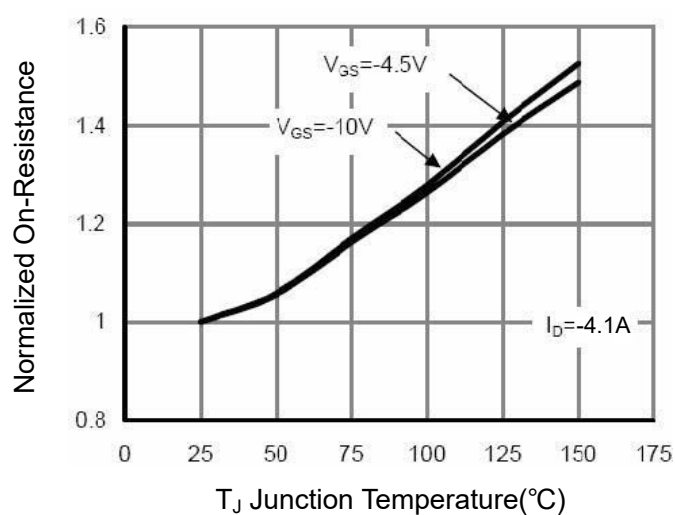
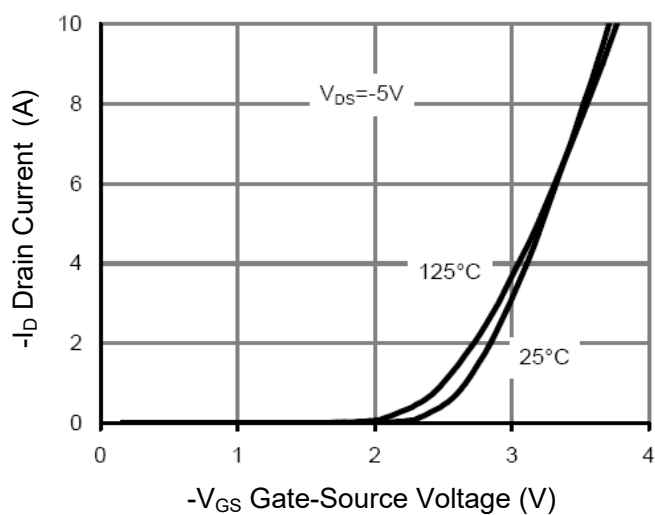
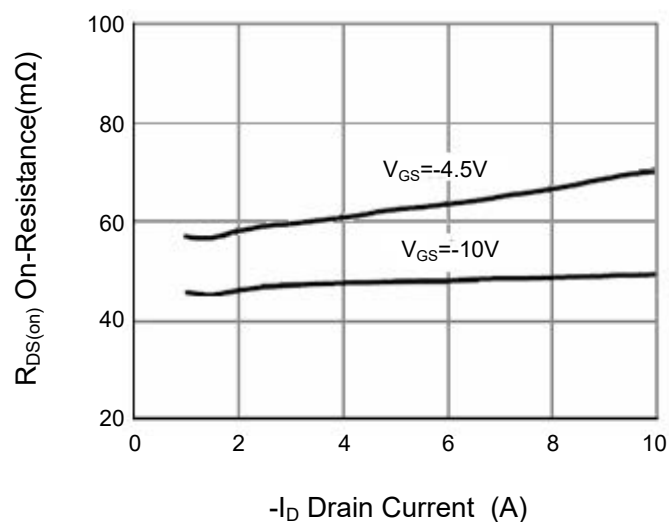
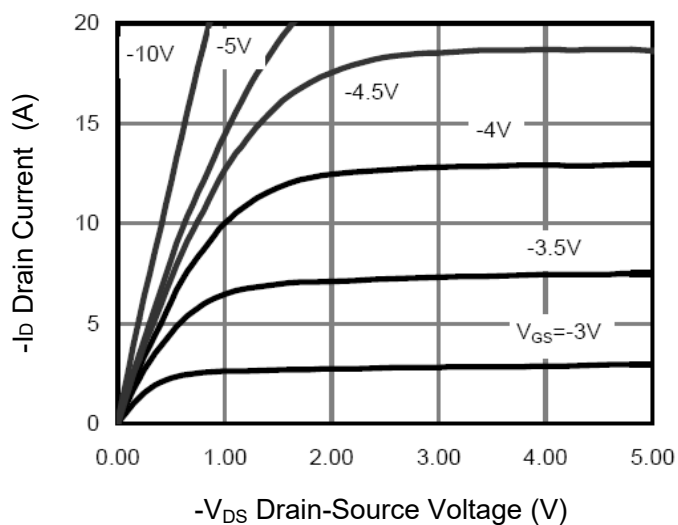
3. Pulse Test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

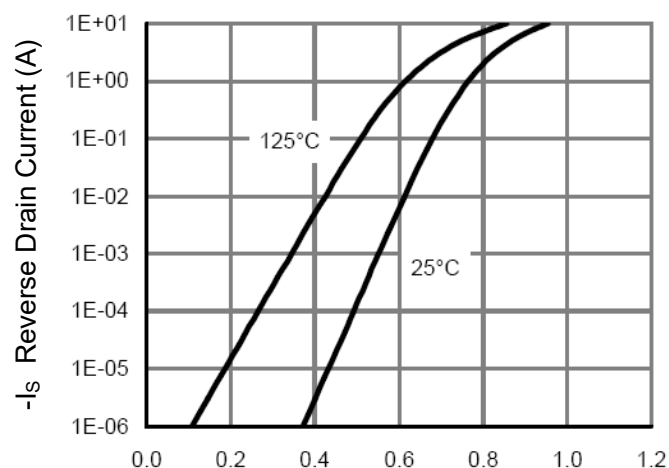
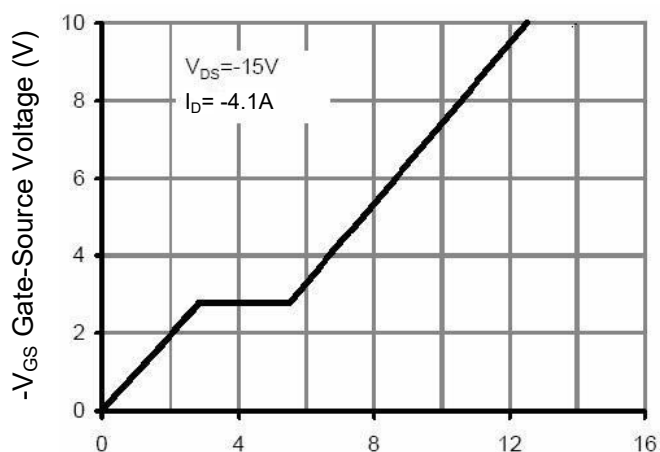
N-Channel Typical Characteristics Curves





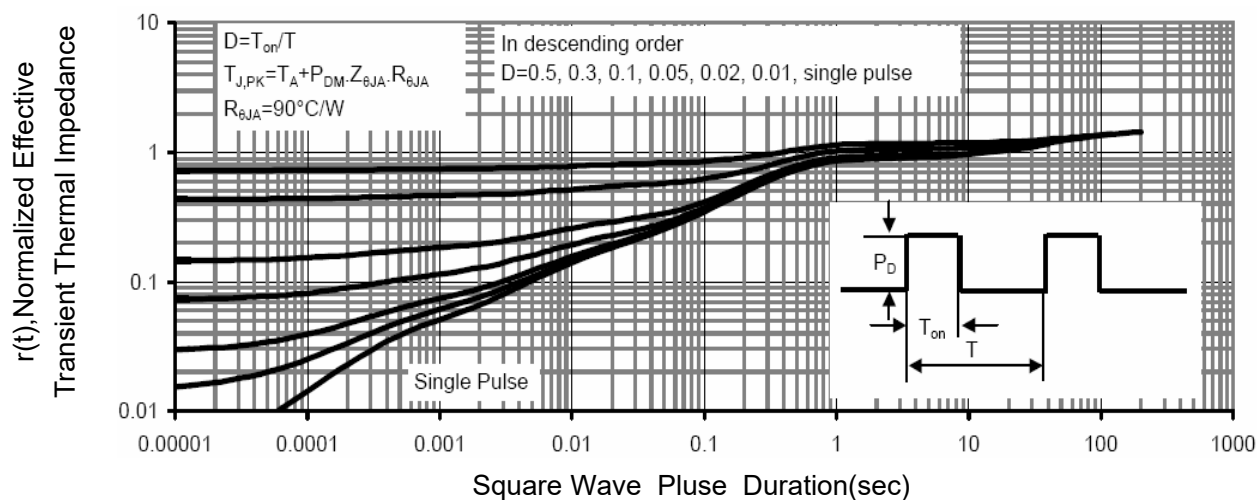
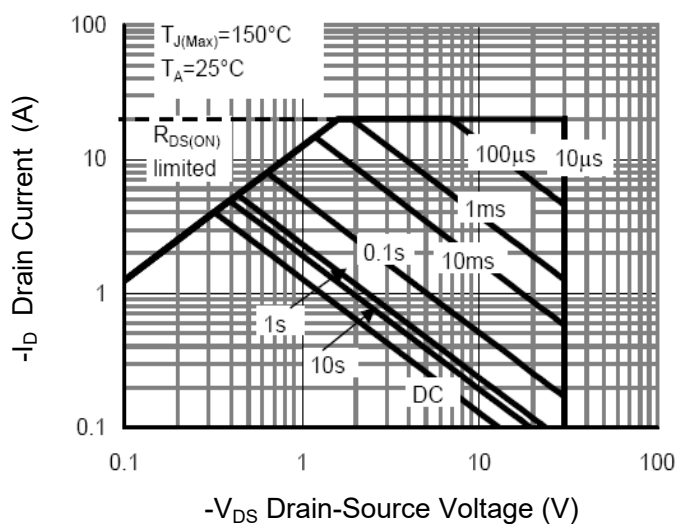
P-Channel Typical Characteristics Curves

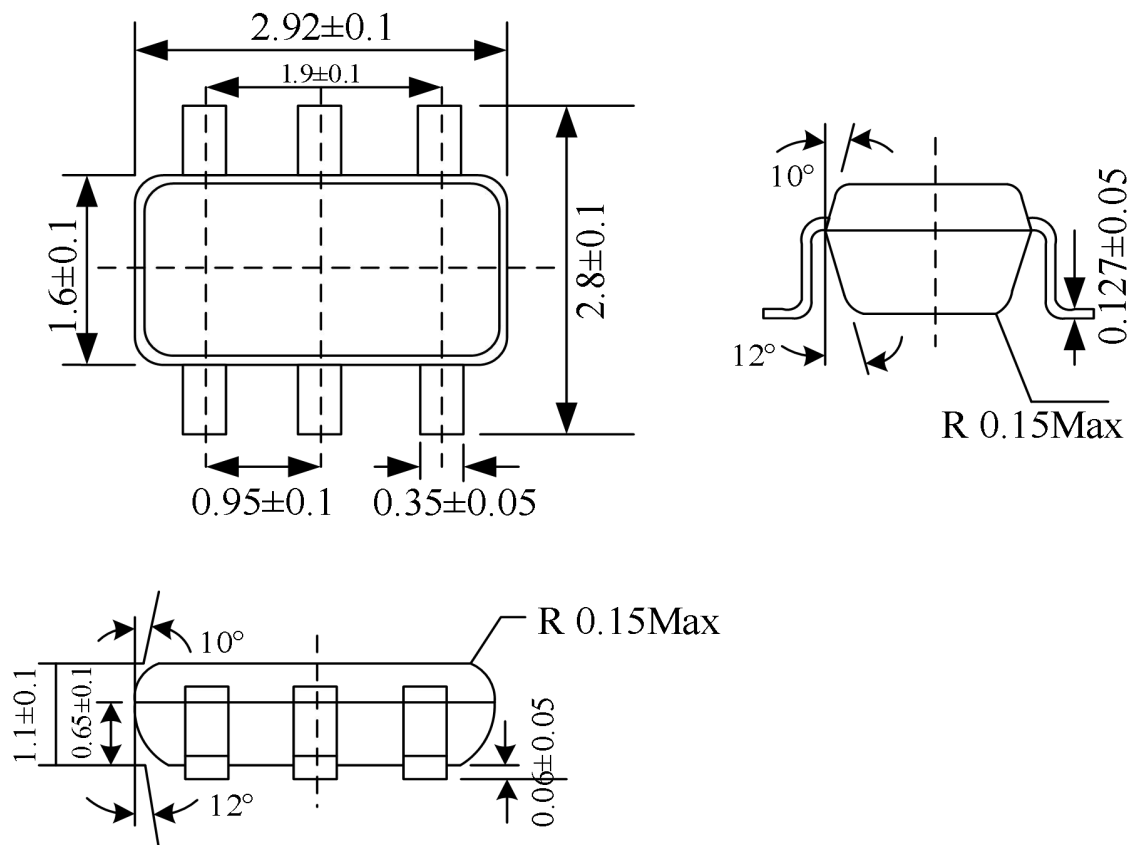




Q_g Gate Charge (nC)

$-V_{DS}$ Drain-Source Voltage (V)

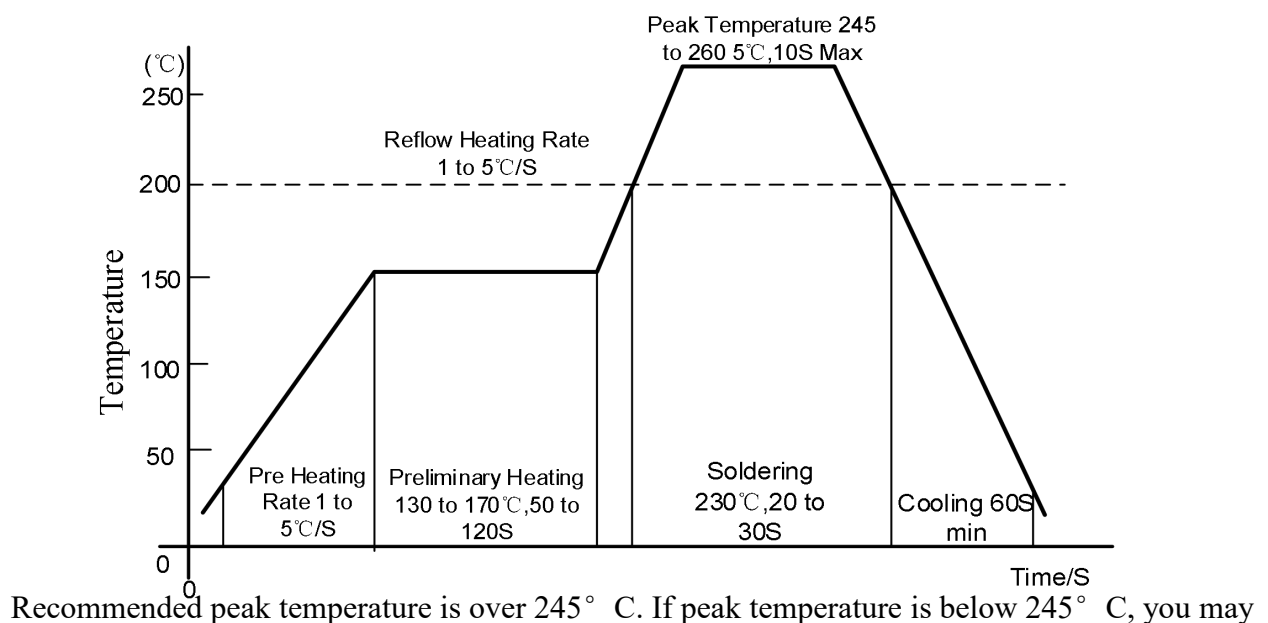


Outline Drawing – SOT-23-6(Dimensions in mm)**Package Information**

Package Type	Description	Quantity (pcs)	Standard
SOT-23-6	Reel -7 inches	3000	EIA-481

Conditions of Soldering and Storage

- Recommended condition of reflow soldering



adjust the following parameters:

- | |
|--|
| • Time length of peak temperature (longer) |
| • Time length of soldering (longer) |
| • Thickness of solder paste (thicker) |

• **Conditions of hand soldering**

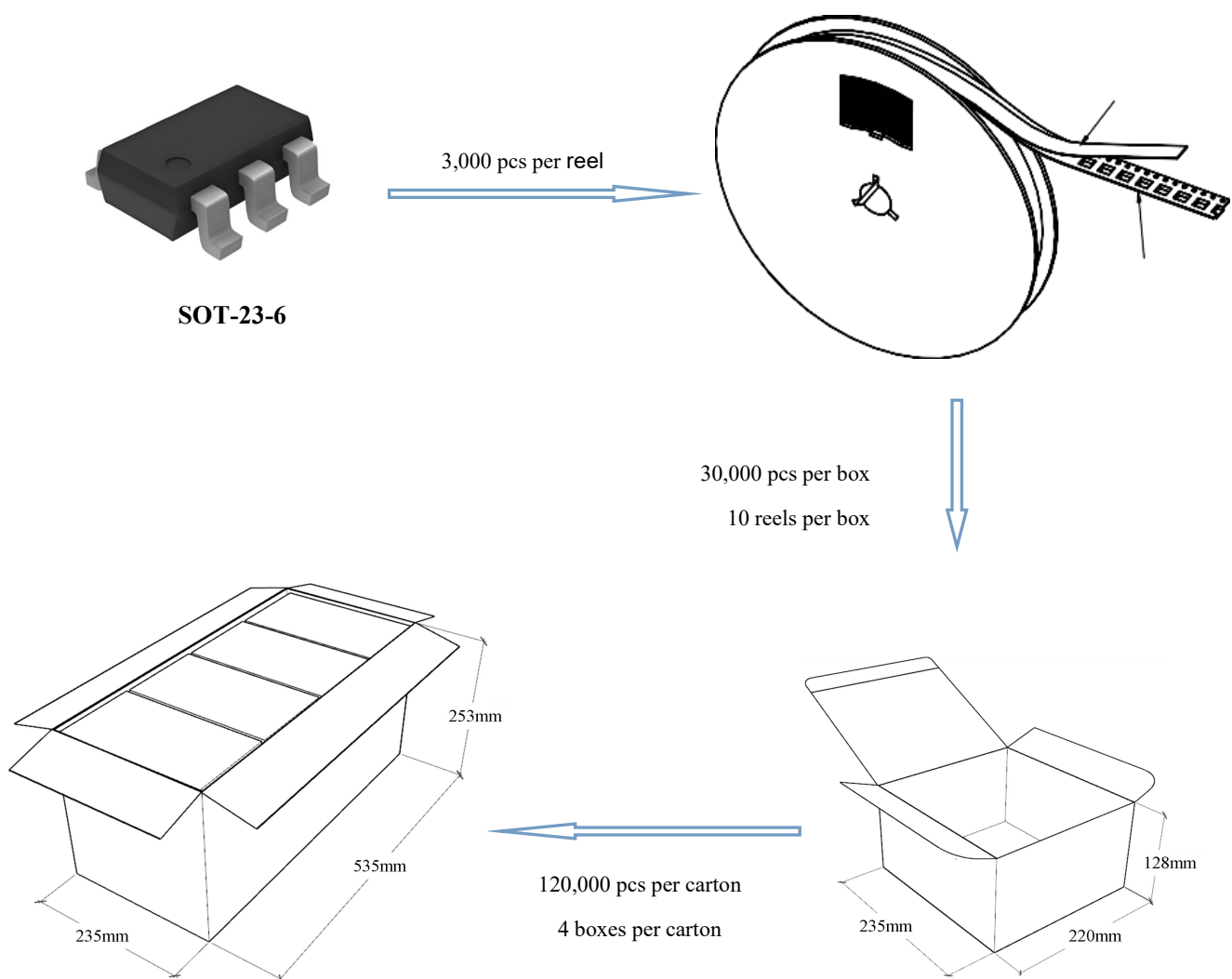
- | |
|----------------------|
| • Temperature: 300°C |
| • Time: 3s max |
| • Times: one time |

• **Storage conditions**

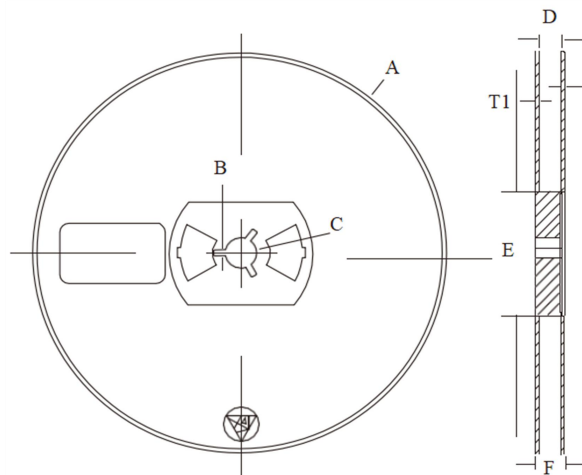
- | |
|--|
| • Temperature: 5 to 40° C |
| • Humidity: 30 to 80% RH |
| • Recommended period: One year after manufacturing |

Package Specifications

• **The method of packaging**

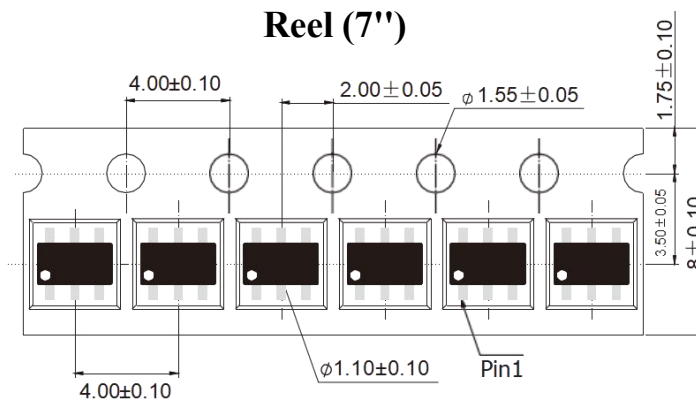


Embossed tape and reel data



Symbol	Value(unit:mm)
A	$\varnothing 177.8 \pm 1$
B	2.7 ± 0.2
C	$\varnothing 13.5 \pm 0.2$
E	$\varnothing 54.5 \pm 0.2$
F	12.3 ± 0.3
D	$9.6 + 2 / - 0.3$
T1	1.0 ± 0.2
T2	1.2 ± 0.2

Reel (7")



Tape (8mm)

Contact Information

TANI website: <http://www.tanisemi.com> Email: tani@tanisemi.com

For additional information, please contact your local Sales Representative.

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Product Specification Statement

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

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